

## Integrated LED Driver with Average-Mode Current Control

### Features

- ▶ 3% accurate LED current
- ▶ Integrated 60V 0.8 $\Omega$  MOSFET
- ▶ Small outline MSOP-8 package
- ▶ Low sensitivity to external component variation
- ▶ Cascode connection with a 500V depletion-mode MOSFET
- ▶ Single resistor LED current setting
- ▶ Fixed off-time control
- ▶ PWM dimming input
- ▶ Output short circuit protection with skip mode
- ▶ Over-temperature protection

### Applications

- ▶ DC/DC or AC/DC LED driver applications
- ▶ RGB backlighting of flat panel displays
- ▶ General purpose constant current source
- ▶ Signage and decorative LED lighting
- ▶ Chargers

### General Description

The HV9967 is an open loop average-mode current control LED driver IC operating in a constant off-time mode.

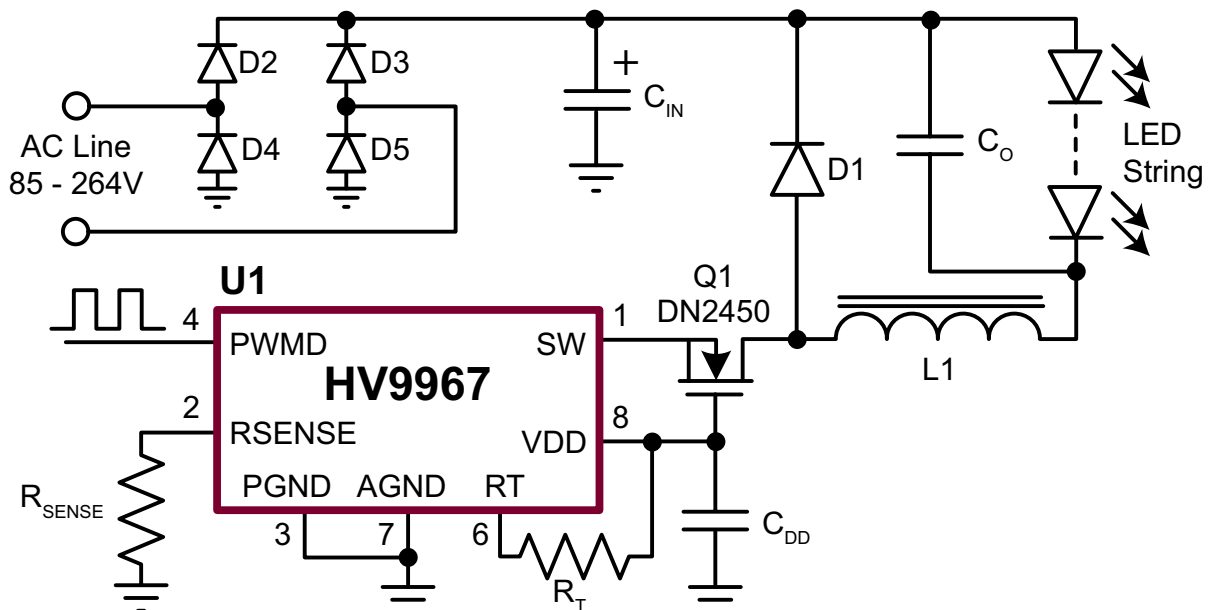
The IC features an integrated 60V 0.8 $\Omega$  MOSFET that can be used as a stand-alone buck converter switch, or connected as a source driver output for driving an external high-voltage depletion-mode MOSFET. The HV9967 is powered through its switching output when the integrated switch is off. Hence, the same external MOSFET can be used as a high-voltage linear regulator deriving the power supply voltage for powering the IC.

The LED current is programmed with one external resistor. The average-mode current control does not produce a peak-to-average error, and therefore greatly improves accuracy, line and load regulation of the LED current without any need for loop compensation or direct sensing the LED current at a high-voltage potential. The auto-zero circuit allows the IC to cancel the effect of both the input offset voltage and the propagation delay in the current sense comparator.

The HV9967 features hiccup-mode short circuit protection and the over-temperature protection.

A PWM dimming input is provided.

### Typical Application Circuit



## Ordering Information

Device	Package Option
	<b>8-Lead MSOP</b> 3.00x3.00mm body 1.10mm height (max) 0.65mm pitch
HV9967	HV9967MG-G

-G indicates package is RoHS compliant ('Green')

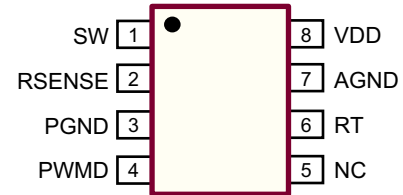


## Absolute Maximum Ratings\*

Parameter	Value
SW to GND	-0.5V to +65V
VDD to GND	-0.3V to 6.0V
Other I/O to GND	-0.3V to ( $V_{DD} + 0.3V$ )
RT, ISET	2.0mA
Continuous power dissipation ( $T_A = +25^\circ C$ )	350mW
Junction temperature	-40°C to +150°C
Storage temperature range	-65°C to +150°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## Pin Configuration



8-Lead MSOP (MG)

## Product Marking

Top Marking



Bottom Marking



L = Lot Number  
 YY = Year Sealed  
 WW = Week Sealed  
 — = "Green" Packaging

Package may or may not include the following marks: Si or

8-Lead MSOP (MG)

## Electrical Characteristics (Specifications are at $T_A = 25^\circ C$ . $V_{IN} = 12V$ , $V_{LD} = V_{DD}$ , $PWMD = V_{DD}$ unless otherwise noted)

Sym	Description	Min	Typ	Max	Units	Conditions
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### Input

$V_{SWDC}$	Input DC supply voltage range	*	8.0	-	60	V	DC input voltage
$I_{INSD}$	Shut-down mode supply current	-	-	0.5	1.0	mA	Pin PWMD to GND

### Internal Regulator

VDD	Internally regulated voltage	-	4.75	5.00	5.25	V	$PWMD = V_{DD}$ ; $R_T = 100k\Omega$
UVLO	$V_{DD}$ undervoltage lockout threshold	*	4.20	-	4.70	V	$V_{DD}$ rising, as needed to ensure $I_{C(MIN)}$
$\Delta UVLO$	$V_{DD}$ undervoltage lockout hysteresis	-	-	150	-	mV	$V_{DD}$ falling

### PWM Dimming

$V_{EN(LO)}$	PWMD input low voltage	*	-	-	0.8	V	---
$V_{EN(HI)}$	PWMD input high voltage	*	2.0	-	-	V	---
$R_{EN}$	Internal Pull Down resistance at PWMD	-	50	100	150	k $\Omega$	$V_{PWMD} = 5.0V$

### Notes:

\* Specifications which apply over the full operating ambient temperature range of  $-40^\circ C < T_A < +85^\circ C$ .

## Electrical Characteristics

Sym	Description	Min	Typ	Max	Units	Conditions
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### Current Control

$V_{CS(TH)}$	RSENSE current threshold	*	243	-	257	mV	---
$T_{BLANK}$	Current sense blanking interval	*	150	-	280	ns	---
$T_{ON(MIN)}$	Minimum on-time	*	-	-	800	ns	$V_{RSENSE} = V_{CS(TH)} + 50mV$
$D_{MAX}$	Maximum steady-state duty cycle	*	80	-	-	%	Reduction in output LED current occurs beyond this duty cycle due to saturation of T2 timers.

### Short Circuit Protection

$V_{CS(SHORT)}$	Hiccup threshold voltage at RSENSE	*	375	-	440	mV	---
$T_{DELAY}$	Current limit delay RSENSE to SW-off	-	-	-	150	ns	$V_{RSENSE} = V_{CS(SHORT)} + 50mV$
$T_{HICCUP}$	Hiccup time	-	-	800	-	$\mu s$	---
$T_{ON(MIN)}$	Minimum on-time (short circuit)	-	-	-	400	ns	$V_{RSENSE} = V_{CS(SHORT)} + 50mV$

### $T_{OFF}$ Timer

$T_{OFF}$	Off time	*	32	40	48	$\mu s$	$R_T = 400k\Omega$
			8.0	10	12		$R_T = 100k\Omega$
			0.8	1.0	1.2		$R_T = 10k\Omega$

### SW Output

$R_{ON}$	On resistance	-	-	0.8	-	$\Omega$	$V_{DD} = 5.0V$
$I_C$	Continuous current	*	0.75	-	-	A	$V_{DD} = 4.75V$ , $V_{RSENSE} = 370mV$ , $V_{SW} = 10V$

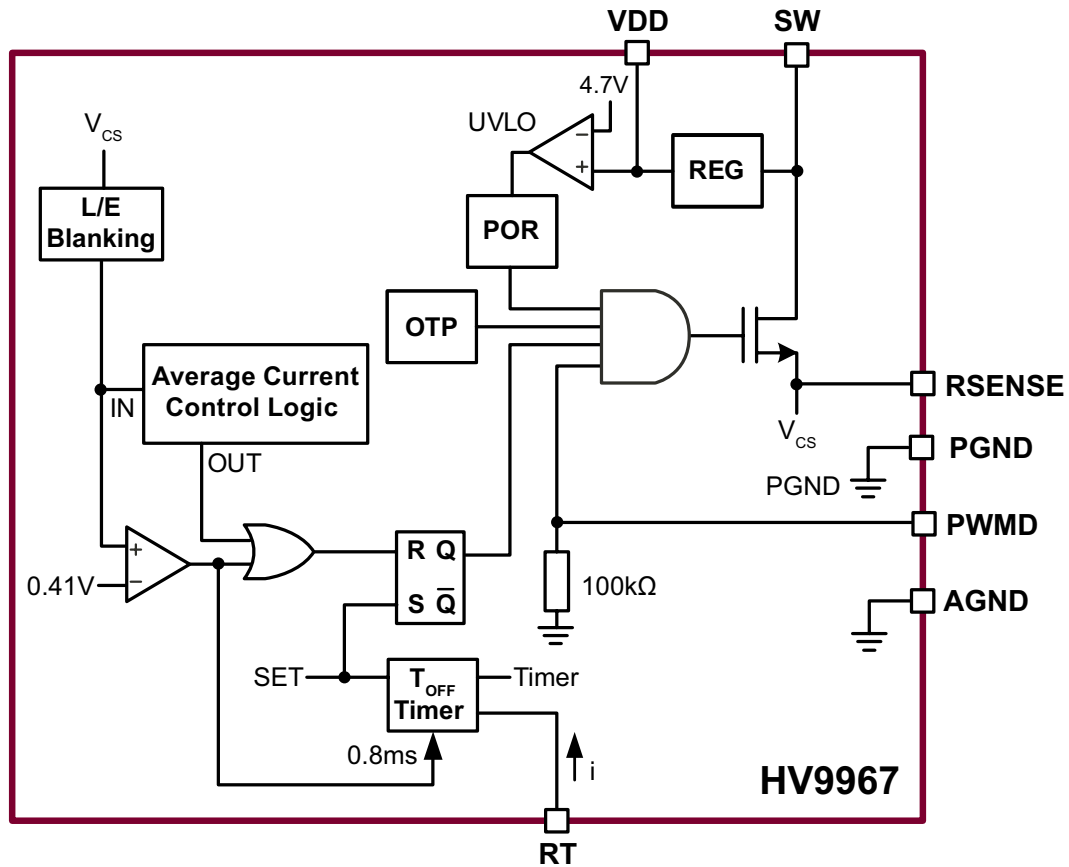
### Over Temperature Protection

$T_{SD}$	Shut-down temperature	-	125	-	-	$^{\circ}C$	---
$\Delta T_{SD}$	Hysteresis	-	-	20	-	$^{\circ}C$	---

#### Notes:

\* Specifications which apply over the full operating ambient temperature range of  $-40^{\circ}C < T_A < +85^{\circ}C$ .

## Functional Block Diagram



## Application Information

### General description

The HV9967 employs Supertex' proprietary control scheme achieving fast and very accurate control of average current in the buck inductor through sensing the switch current only. No compensation of the current control loop is required. The LED current response to PWMMD input is similar to that of the peak-current control ICs, such as HV9910B. The inductor current ripple amplitude does not affect this control scheme significantly, and therefore, the LED current is independent of the variation in inductance, switching frequency or output voltage. Constant off-time control of the buck converter is used for stability and to reduce input voltage regulation of the LED current.

### OFF Timer

The timing resistor connected to RT determines the off-time of the gate driver, and it must be wired to VDD. The equation governing the off-time of the GATE output is given by:

$$T_{OFF} = R_T \cdot 100pF \quad (1)$$

within the range of  $10k\Omega \leq R_T \leq 400k\Omega$ .

### Average Current Control Feedback and Output Short Circuit Protection

The constant-current control feedback derives the average current signal from the source current of the switching MOSFET. This current is detected using a sense resistor at the RSENSE pin. The feedback operates in a fast open-loop mode. No compensation is required. Output current is programmed simply as:

$$I_{LED} = \frac{0.25V}{R_{CS}} \quad (2)$$

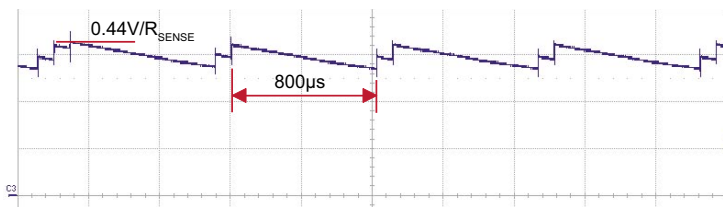
The above equation is only valid for continuous conduction of the output inductor. It is a good practice to design the inductor such that the switching ripple current in it is 30~40% of its average full load DC current peak-to-peak. Hence, the recommended inductance can be calculated as:

$$L_O = \frac{V_{O(MAX)} \cdot T_{OFF}}{0.4 \cdot I_O} \quad (3)$$

The duty-cycle range of the current control feedback is limited to  $D \leq 0.8$ . A reduction in the LED current may occur when the LED string voltage  $V_O$  is greater than 80% of the input voltage  $V_{IN}$  of the HV9967 LED driver.

Reducing the output LED voltage  $V_O$  below  $V_{O(MIN)} = V_{IN} \cdot D_{MIN}$ , where  $D_{MIN} = 0.8\mu s / (T_{OFF} + 0.8\mu s)$ , may also result in the loss of regulation of the LED current. This condition, however, causes increase in the LED current and can potentially trip the short-circuit protection comparator threshold.

The short circuit protection comparator trips when the voltage at RSENSE exceeds 0.41V. When this occurs, the SW off-time  $T_{HICCUP} = 800\mu s$  is generated to prevent stair-casing of the inductor current and potentially its saturation due to insufficient output voltage. The typical short-circuit current is shown in the waveform of Fig. 1.



A leading-edge blanking delay is provided at RSENSE to prevent false triggering of the current feedback and the short circuit protection.

## SW Output and Linear Regulator

The HV9967 includes an integrated 60V 0.8Ω switching MOSFET at the SW output, that could be used as a stand-alone switch for low-volt DC input applications, or as a source driver of an external depletion mode MOSFET (for example, DN2450 by Supertex). In both cases, the power for the IC is supplied from a linear 5.0V regulator that is also derived from the SW input.

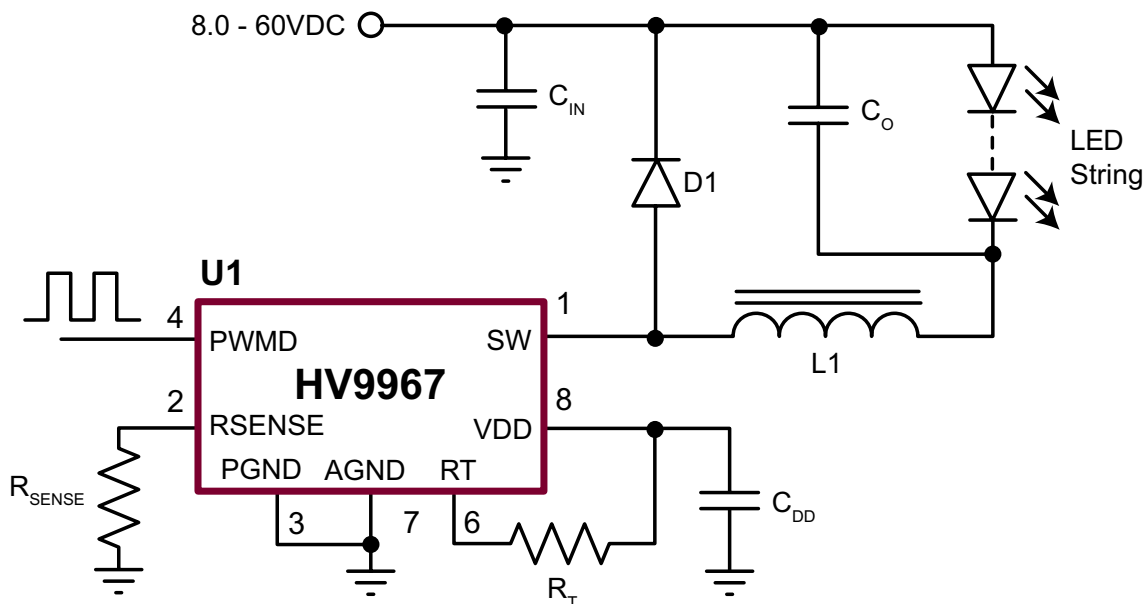
## PWM Dimming

The HV9967 features a TTL compatible dimming input PWMD. Applying a square-wave voltage to PWMD will modulate the duty ratio of the LED current accordingly. The rising and falling edges are limited by the current slew rate in the inductor. The first switching cycle is terminated upon reaching the 250mV level at RSENSE. The circuit will further reach the steady state within 3~4 switching cycles regardless of the switching frequency.

## Over-Temperature Protection

The HV9967 includes over-temperature protection. Typically, when the junction temperature exceeds 145°C, switching of the SW input is disabled. The switching resumes when the temperature falls by approximately 20°C from the trip point.

## Alternative Typical Application (low-voltage DC input)

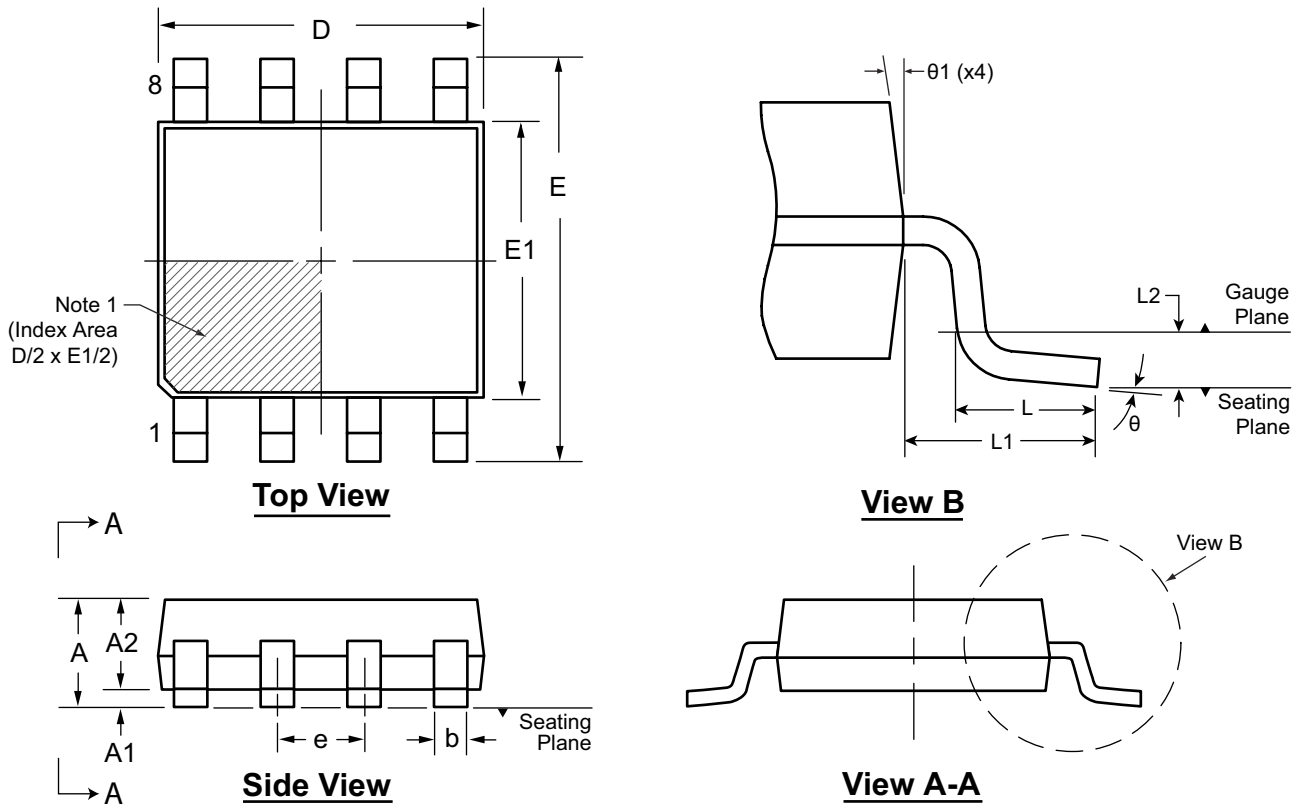


## Pin Description

Pin #	Function	Description
1	SW	Drain of 60V 0.8Ω NDMOS switch and input of H/V regulator.
2	RSENSE	Source of NDMOS switch and current sense input. Connect a resistor to GND to program the output current and short circuit thresholds.
3	PGND	Power ground. Must be wired to AGND on PCB.
4	PWMD	PWM dimming input. This TTL input enables switching of SW when in high state.
5	NC	No connection.
6	RT	Resistor connected between RT and VDD programs the off-time of SW.
7	AGND	Analog ground (0V).
8	VDD	Power supply for all internal circuits. Bypass with a low ESR capacitor to PGND (>0.5μF). Connect gate of external depletion-mode NFET for high-voltage operation.

# 8-Lead MSOP Package Outline (MG)

3.00x3.00mm body, 1.10mm height (max), 0.65mm pitch



**Note:**  
1. A Pin 1 identifier must be located in the index area indicated. The Pin 1 identifier can be: a molded mark/identifier; an embedded metal marker; or a printed indicator.

Symbol		A	A1	A2	b	D	E	E1	e	L	L1	L2	θ	θ1
Dimension (mm)	MIN	0.75*	0.00	0.75	0.22	2.80*	4.65*	2.80*	0.65 BSC	0.40	0.95 REF	0.25 BSC	0°	5°
	NOM	-	-	0.85	-	3.00	4.90	3.00		0.60			-	-
	MAX	1.10	0.15	0.95	0.38	3.20*	5.15*	3.20*		0.80			8°	15°

JEDEC Registration MO-187, Variation AA, Issue E, Dec. 2004.

\* This dimension is not specified in the JEDEC drawing.

Drawings are not to scale.

Supertex Doc. #: DSPD-8MSOPMG, Version H041309.

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <http://www.supertex.com/packaging.html>.)

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